

OKI Semiconductor

1A

MR27V852D

524,288-Word x 16-Bit or 1,048,576-Word x 8-Bit

8-Word x 16-Bit or 16-Word x 8-Bit Page Mode One Time PROM

DESCRIPTION

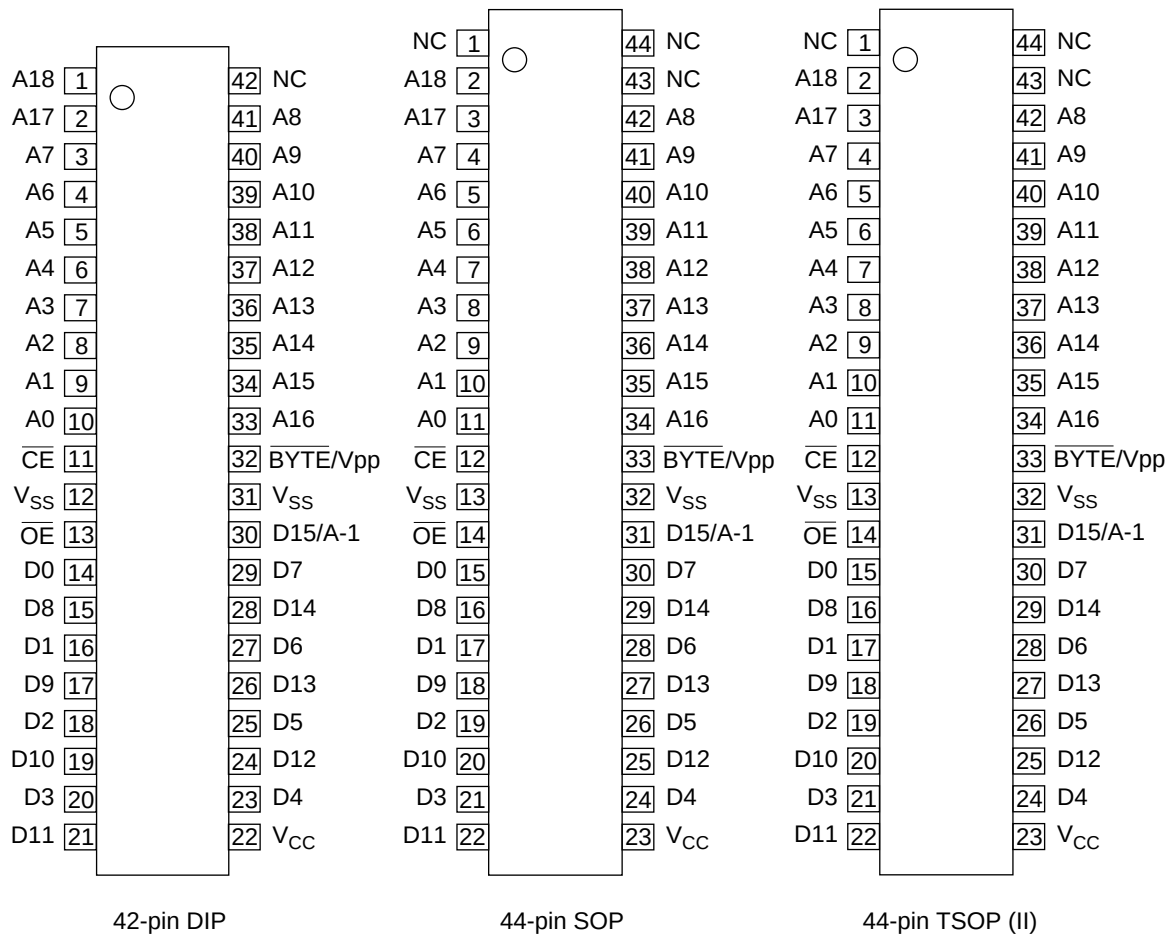
The MR27V852D is a 8Mbit electrically Programmable Read-Only Memory with page mode. Its configuration can be electrically switched between 524,288 word x 16bit and 1,048,576 word x 8bit. The MR27V852D operates on a single +3.3V power supply and is TTL compatible. The MR27V852D provides Page mode which can greatly reduce the read access time. Since the MR27V852D operates asynchronously, external clocks are not required, making this device easy-to-use. The MR27V852D is suitable as large-capacity fixed memory for microcomputers and data terminals. It is manufactured using a CMOS double silicon gate technology and is offered in 42-pin DIP, 44-pin SOP or 44-pin TSOP packages.

FEATURES

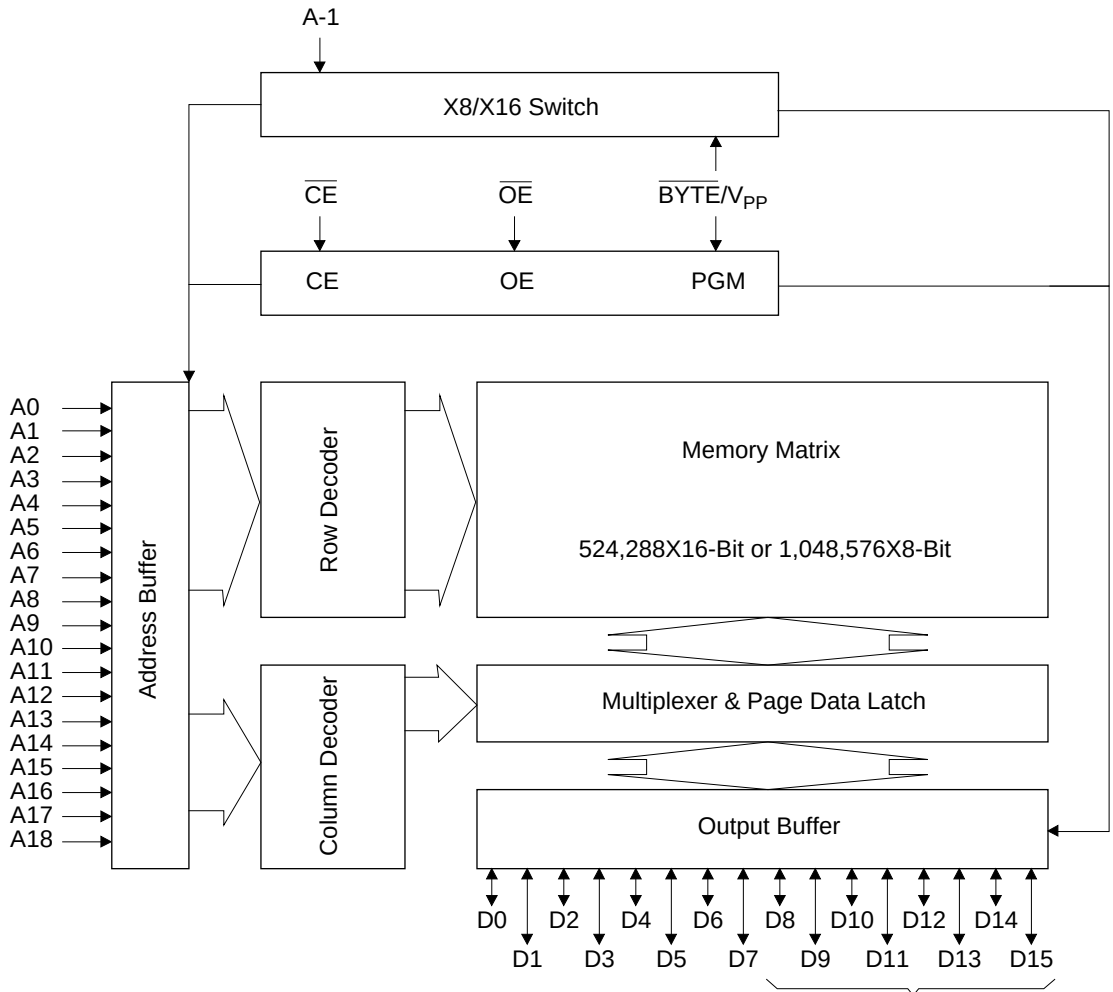
- 524,288 word x 16bit / 1,048,576 word x 8bit electrically switchable configuration
- Single +3.3V power supply
- Access time 80ns
Page mode access time 30ns
- Input / Output TTL compatible
- Three-state output
- Packages

42-pin plastic DIP (DIP42-P-600-2.54) (Product name : MR27V852DRA)
44-pin plastic SOP (SOP44-P-600-1.27-K) (Product name : MR27V852DMA)
44-pin plastic TSOP (TSOP II 44-P-400-0.80-K) (Product name : MR27V852DTP)

PIN CONFIGURATION (TOP VIEW)



PIN NAMES	FUNCTIONS
D15/A-1	Data output / Address input
A0 - A18	Address input
D0 - D14	Data output
$\overline{CE}$	Chip enable
$\overline{OE}$	Output enable
V_{CC}	Power supply voltage
V_{SS}	GND
BYTE/ V_{PP}	Mode switch / Program power supply voltage
NC	Non connection

BLOCK DIAGRAM

In 8-bit output mode, these pins are three-stated and pin D15 functions as the A-1 address pin.

FUNCTION TABLE

MODE	$\overline{\text{CE}}$	$\overline{\text{OE}}$	$\overline{\text{BYTE}}/\text{V}_{\text{PP}}$	V_{CC}	D0 - D7	D8 - D14	D15/A-1
READ (16-Bit)	L	L	H	3.3V	D_{OUT}		
READ (8-Bit)	L	L	L		D_{OUT}	Hi-Z	L/H
OUTPUT DISABLE	L	H	H		Hi-Z		
			L		*		
STAND-BY	H	*	H		Hi-Z		
			L		*		
PROGRAM	L	H	9.75V	4.0V	D_{IN}		
PROGRAM INHIBIT	H	H			Hi-Z		
PROGRAM VERIFY	H	L			D_{OUT}		

* : Don't Care

ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Condition	Value	Unit
Operating temperature under bias	T _{opr}	-	0 to 70	°C
Storage temperature	T _{stg}		-55 to 125	°C
Input voltage	V _I	relative to V _{SS}	-0.5 to V _{CC} + 0.5	V
Output voltage	V _O		-0.5 to V _{CC} + 0.5	V
Power supply voltage	V _{CC}		-0.5 to 5	V
Program power supply voltage	V _{PP}		-0.5 to 11.5	V
Power dissipation per package	P _D	-	1.0	W

RECOMMENDED OPERATING CONDITIONS FOR READ

(Ta=0 to 70°C)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
V _{CC} power supply voltage	V _{CC}	V _{CC} =3.0V-3.6V	3.0	-	3.6	V
V _{PP} power supply voltage	V _{PP}		-0.5	-	V _{CC} +0.5	V
Input "H" level	V _{IH}		2.2	-	V _{CC} +0.5*	V
Input "L" level	V _{IL}		-0.5**	-	0.6	V

Voltage is relative to Vss

* : Vcc+1.5V (Max.) when pulse width of overshoot is less than 10nS.

** : -1.5V (Min.) when pulse width of undershoot is less than 10nS.

ELECTRICAL CHARACTERISTICS (Read operation)**DC Characteristics**(V_{CC}=3.3V±0.3V, Ta=0 to 70°C)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Input leakage current	I _{LI}	V _I =0 to V _{CC}	-	-	10	μA
Output leakage current	I _{LO}	V _O =0 to V _{CC}	-	-	10	μA
V _{CC} power supply current (Standby)	I _{CS1}	$\overline{CE}=V_{CC}$	-	-	50	μA
	I _{CS2}	$\overline{CE}=V_{IH}$	-	-	1	mA
V _{CC} power supply current (Read)	I _{CCA}	$\overline{CE}=V_{IL}$, $\overline{OE}=V_{IH}$ tc=80ns	-	-	80	mA
V _{PP} power supply current	I _{PP}	V _{PP} =V _{CC}	-	-	10	μA
Input "H" level	V _{IH}	-	2.2	-	V _{CC} +0.5*	V
Input "L" level	V _{IL}	-	-0.5**	-	0.6	V
Output "H" level	V _{OH}	I _{OH} =-400μA	2.4	-	-	V
Output "L" level	V _{OL}	I _{OL} =2.1mA	-	-	0.4	V

Voltage is relative to Vss

* : V_{CC}+1.5V (Max.) when pulse width of overshoot is less than 10nS.

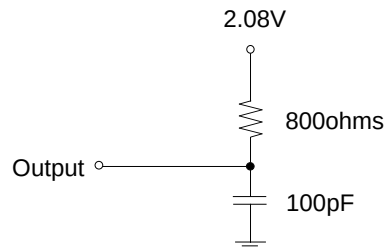
** : -1.5V (Min.) when pulse width of undershoot is less than 10nS.

AC Characteristics(V_{CC}=3.3V±0.3V, Ta=0 to 70°C)

Parameter	Symbol	Condition	Min.	Max.	Unit
Address access cycle time	T _C	-	80	-	ns
Address access time	T _{ACC}	$\overline{CE}=\overline{OE}=V_{IL}$	-	80	ns
Page access cycle time	T _{PC}	-	30	-	ns
Page access time	T _{PAC}	-	-	30	ns
$\overline{CE}$ access time	T _{CE}	$\overline{OE}=V_{IL}$	-	80	ns
$\overline{OE}$ access time	T _{OE}	$\overline{CE}=V_{IL}$	-	30	ns
Output disable time	T _{CHZ}	$\overline{OE}=V_{IL}$	0	30	ns
	T _{OHZ}	$\overline{CE}=V_{IL}$	0	25	ns
Output hold time	T _{OH}	$\overline{CE}=\overline{OE}=V_{IL}$	0	-	ns

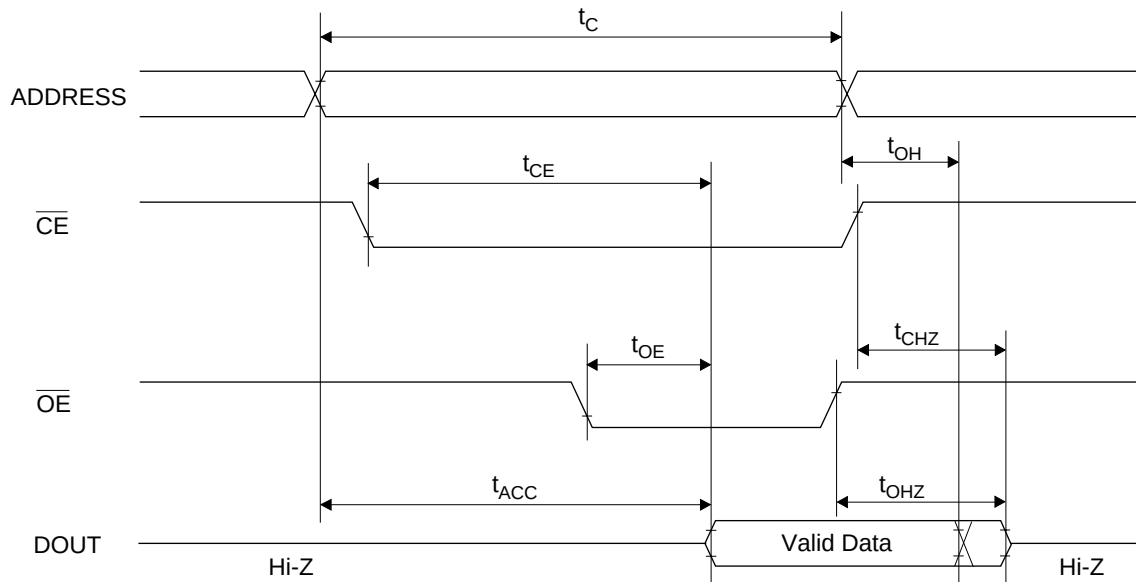
Measurement conditions

Input signal level ----- 0V/3V
 Input timing reference level ----- 0.8V/2.0V
 Output load ----- 100pF
 Output timing reference level ----- 0.8V/2.0V

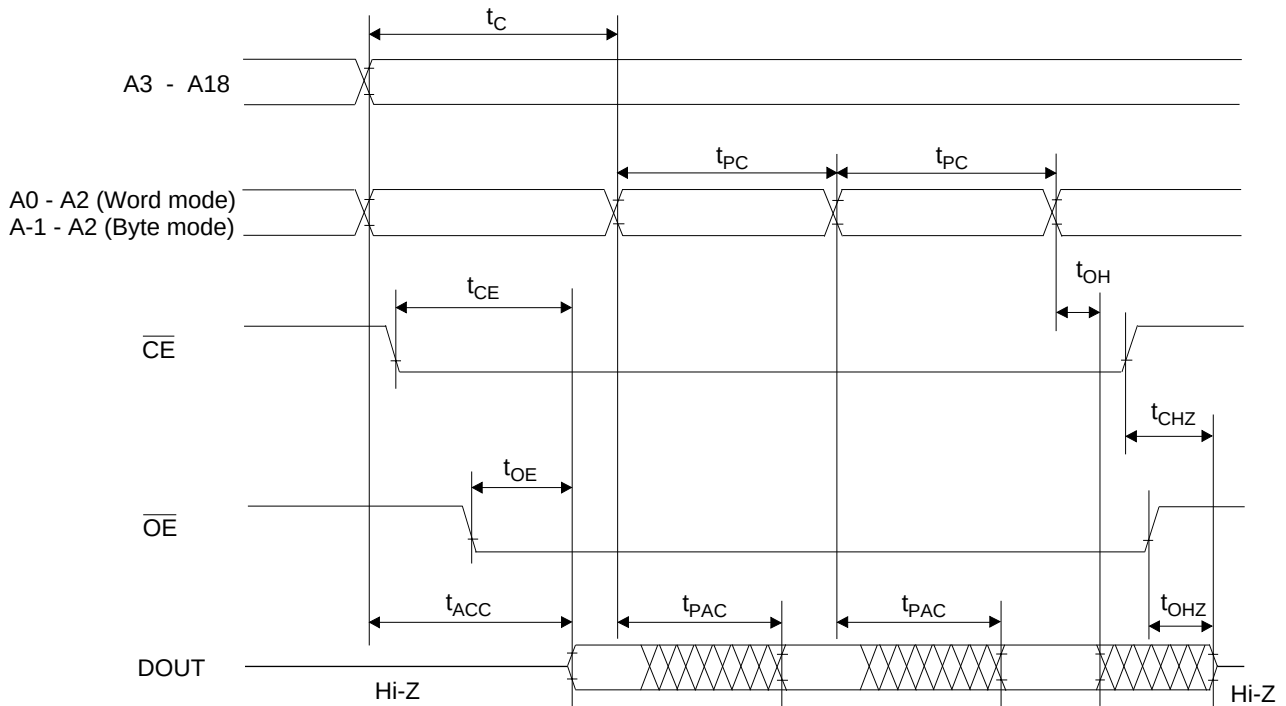


TIMING CHART

NORMAL MODE READ CYCLE



PAGE MODE READ CYCLE



ELECTRICAL CHARACTERISTICS (Programming operation)

DC Characteristics

(Ta=25°C±5°C)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Input leakage current	I _{LI}	V _I =V _{CC} +0.5V	-	-	10	μA
V _{PP} power supply current (Program)	I _{PP2}	$\overline{CE}=V_{IL}$	-	-	50	mA
V _{CC} power supply current	I _{CC}	-	-	-	80	mA
Input "H" level	V _{IH}	-	3.0	-	V _{CC} +0.5	V
Input "L" level	V _{IL}	-	-0.5	-	0.8	V
Output "H" level	V _{OH}	I _{OH} =-400μA	2.4	-	-	V
Output "L" level	V _{OL}	I _{OL} =2.1mA	-	-	0.45	V
Program voltage	V _{PP}	-	9.5	9.75	10.0	V
V _{CC} power supply voltage	V _{CC}	-	3.9	4.0	4.1	V

Voltage is relative to Vss

AC Characteristics

(V_{CC}=4.0V±0.1V, V_{pp}=9.75V±0.25V, Ta=25°C±5°C)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Address set-up time	T _{AS}	-	100	-	-	ns
$\overline{OE}$ set-up time	T _{OES}	-	2	-	-	μs
Data set-up time	T _{DS}	-	100	-	-	ns
Address hold time	T _{AH}	-	2	-	-	μs
Data hold time	T _{DH}	-	100	-	-	ns
Output float delay from $\overline{OE}$	T _{OHZ}	-	0	-	100	ns
V _{PP} voltage set-up time	T _{VS}	-	2	-	-	μs
Program pulse width	T _{PW}	-	9	10	11	μs
Data valid from $\overline{OE}$	T _{OE}	-	-	-	100	ns
Address hold from $\overline{OE}$ high	T _{AHO}	-	0	-	-	ns

Pin Check Function

Pin Check Function is to check contact between each device-pin and each socket-lead with EPROM programmer.

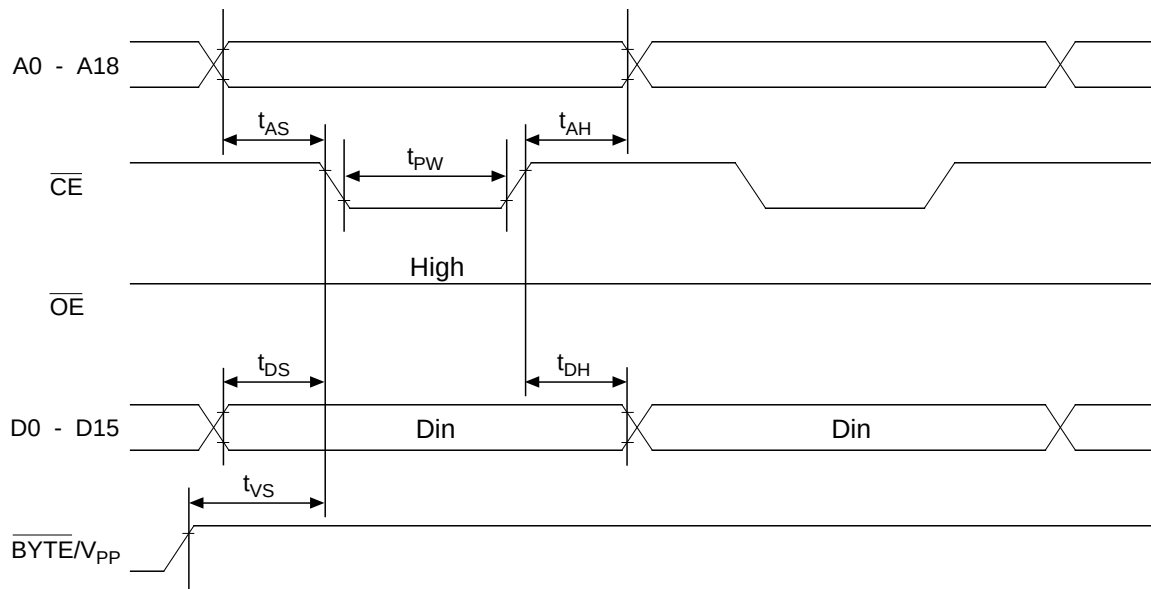
Setting up address as the following condition call the preprogrammed codes on device outputs.

(V_{CC}=3.3V±0.3V, $\overline{CE}=\overline{OE}=V_{IL}$, $\overline{BYTE}/V_{pp}=V_{IH}$, Ta=25°C±5°C)

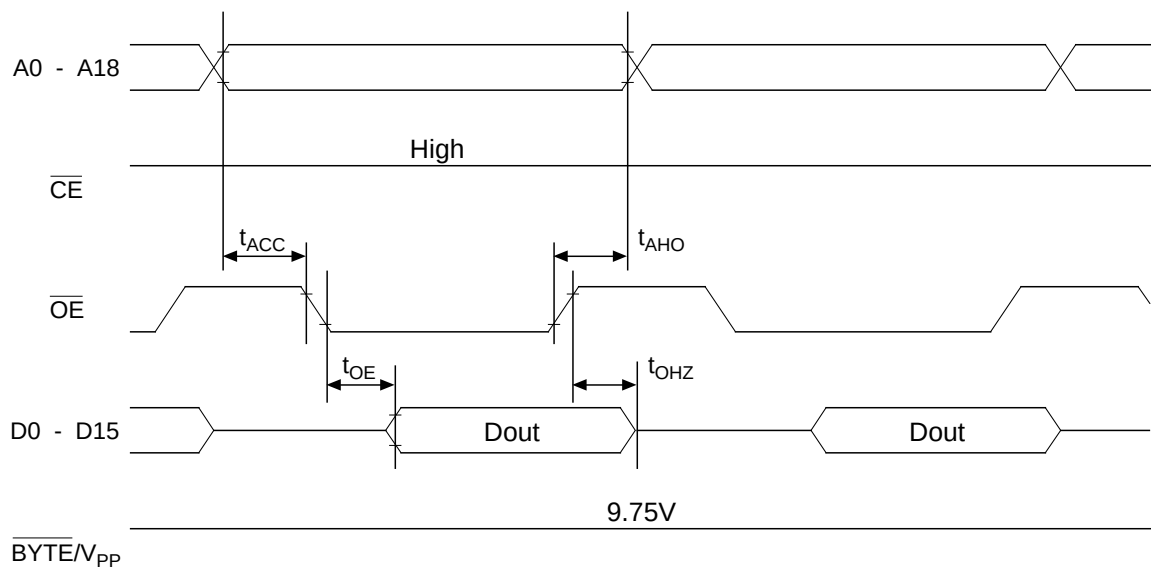
A0	A1	A2	A3	A4	A5	A6	A7	A8	A9	A10	A11	A12	A13	A14	A15	A16	A17	A18	DATA
0	1	0	1	0	1	0	1	0	VH*	0	1	0	1	0	1	0	0	1	FF00
1	0	1	0	1	0	1	0	1	VH*	1	0	1	0	1	0	1	1	0	00FF
Other conditions																			FFFF

* :VH=8V±0.25V

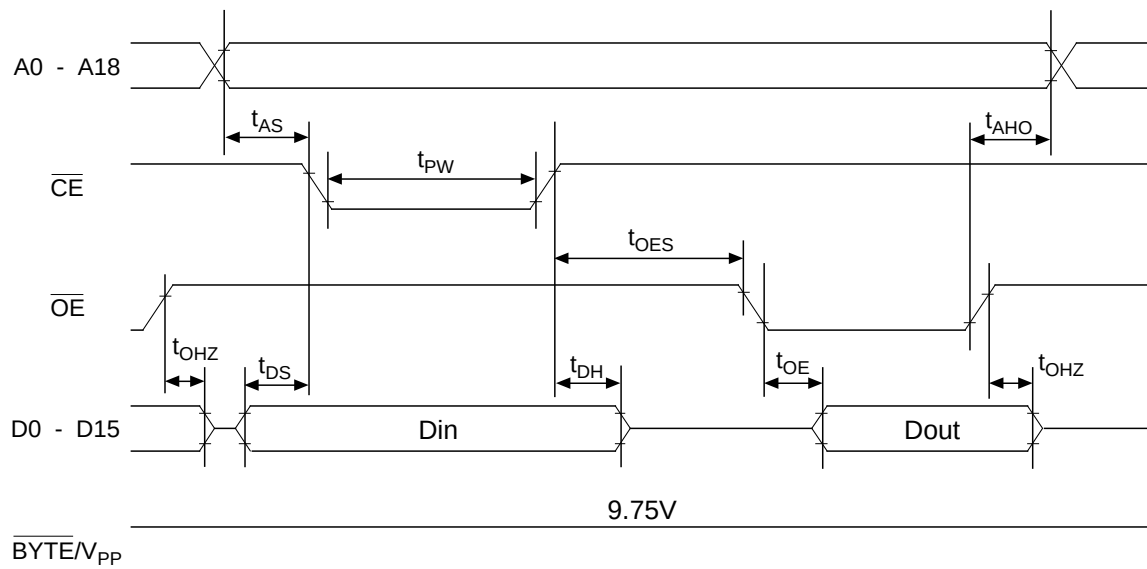
Consecutive Programming Waveforms



Consecutive Program Verify Waveforms



Program and Program Verify Cycle Waveforms



PIN Capacitance

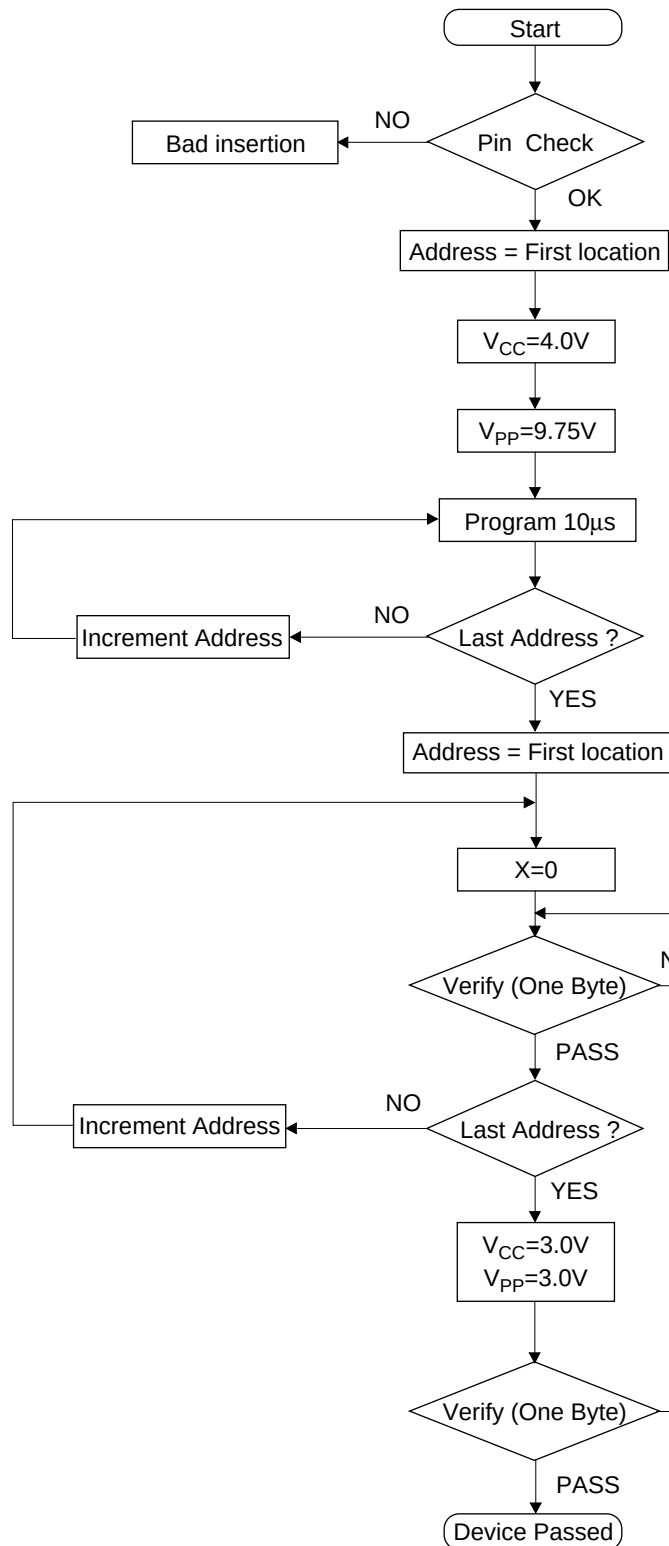
($V_{CC}=3.3V$, $T_a=25^{\circ}C$, $f=1MHz$)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Input	C_{IN1}	$V_I=0V$	-	-	8 (10)	pF
$\overline{BYTE}/V_{PP}$	C_{IN2}		-	-	120	
Output	C_{OUT}	$V_O=0V$	-	-	10 (12)	

() : DIP only

Programming / Verify Flow Chart

Programming



Verify

